

## 产品规格书

Specification of products

产品名称：整流管模块

产品型号：MDK40A1600V-T03

浙江世菱半导体有限公司  
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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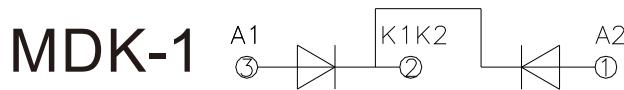
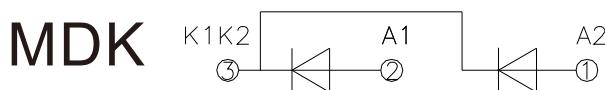
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拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j$ (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean for ward current	180° half sine wave 50Hz Single side cooled, $T_C = 100^\circ\text{C}$	150			40	A
$I_{F(RMS)}$	RMS for ward current	Single side cooled, $T_C = 100^\circ\text{C}$	150			63	A
$V_{RRM}$	Repetitive peak reverse voltage	$V_{RRM}$ tp=10ms $V_{RsM} = V_{DRM} \& V_{RRM} + 200\text{V}$	150	600	1600	1800	V
$I_{RRM}$	Repetitive peak current	at $V_{RRM}$	150			8	mA
$I_{FSM}$	Surge for ward current	10ms half sine wave	150			1.30	KA
$I^2t$	$I^2t$ for fusing coordination	$V_R = 0.6V_{RRM}$				8.6	$\text{A}^2\text{s} \times 10^3$
$V_{FO}$	Threshold voltage		150			0.80	V
$r_F$	Forward slop resistance					3.47	$\text{m}\Omega$
$V_{FM}$	Peak for ward voltage	$I_{FM} = 120\text{A}$	25			1.1	V
$R_{th(j-c)}$	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.700	$^\circ\text{C}/\text{W}$
$V_{iso}$	Isolation voltage	50Hz, RM. S, t=1min, $I_{iso}$ : 1mA (max)		2500			V
$F_m$	Terminal connection torque( M5)				4.0		N.m
	Mounting torque( M6)				5.0		N.m
$T_{Stg}$	Stored temperature			-40		125	$^\circ\text{C}$
$W_t$	Weight				110		g
Outline							

## OUTLINE DRAWING & CIRCUIT DIAGRAM



## Rating and Characteristic

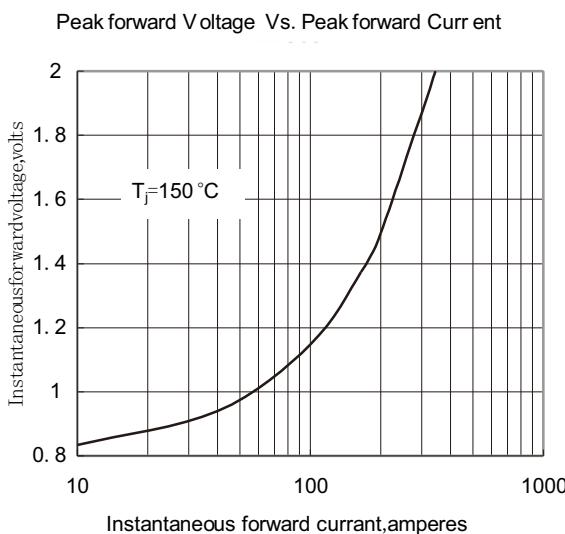


Fig. 1

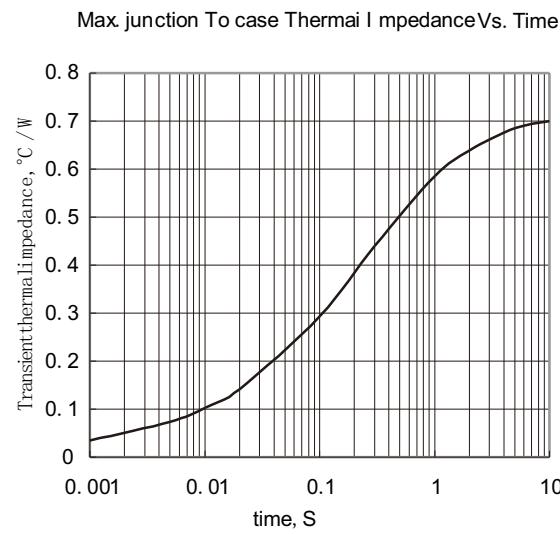


Fig. 2

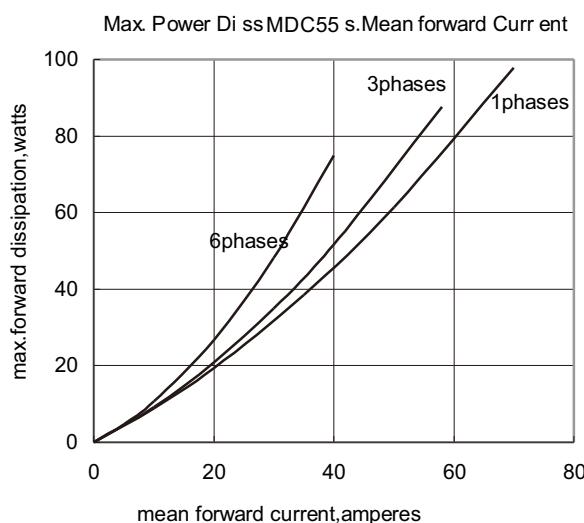


Fig. 3

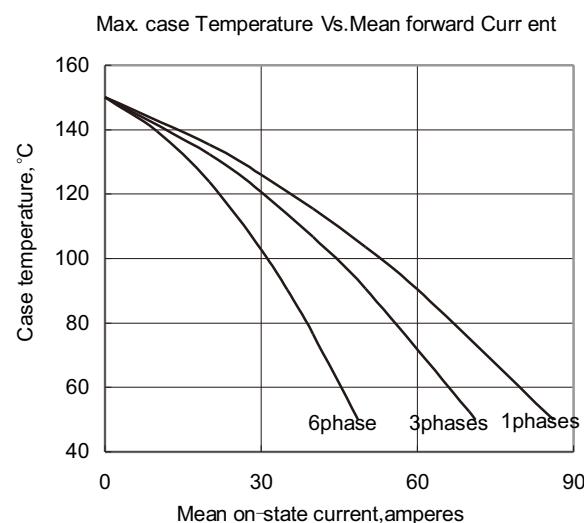


Fig. 4

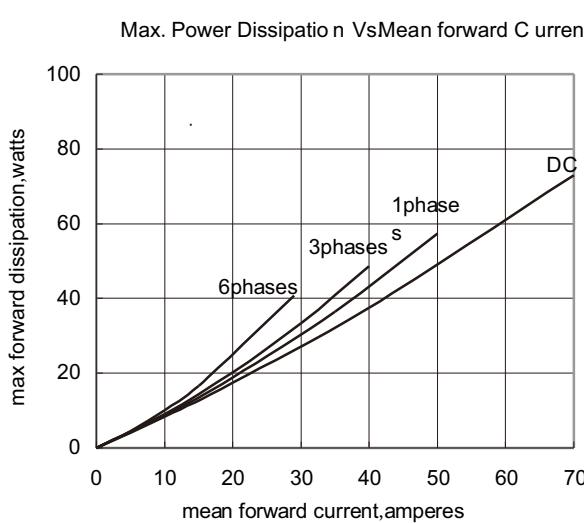


Fig. 5

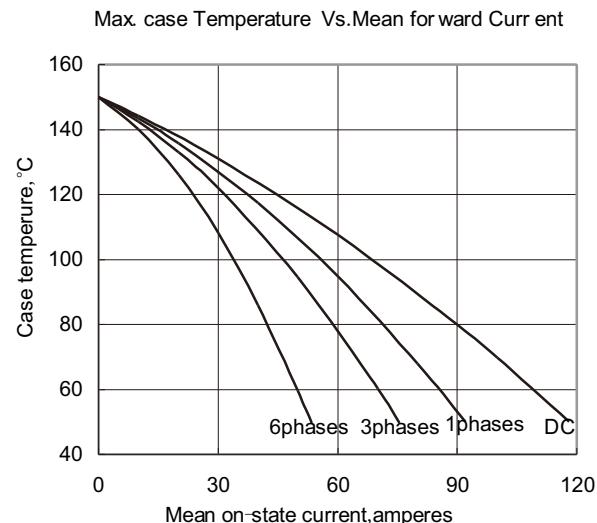


Fig. 6

## Outside Dimension

